

MURB1620CTR

Preferred Device

SWITCHMODE™ Power Rectifier

D²PAK Power Surface Mount Package

... designed for use in negative switching power supplies, inverters and as free wheeling diodes. Also, used in conjunction with common cathode dual Ultrafast Rectifiers, makes a single phase full-wave bridge. These state-of-the-art devices have the following features:

- Common Anode Dual Rectifier (8.0 A per Leg or 16 A per Package)
- Ultrafast 35 Nanosecond Reverse Recovery Times
- Exhibits Soft Recovery Characteristics
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Epoxy Meets UL94, V_O @ 1/8"
- Complement to MURB1620CT Common Cathode Device

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.7 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Available in 24 mm Tape and Reel, 800 units per reel by adding a "T4" suffix to the part number
- Marking: U1620R

MAXIMUM RATINGS (Per Leg)

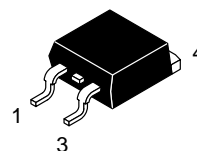
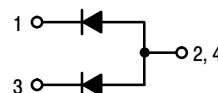
Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
Average Rectified Forward Voltage (Rated V_R , $T_C = 160^\circ\text{C}$) Per Leg Per Total Device	$I_{F(AV)}$	8.0 16	A
Peak Repetitive Surge Current (Rated V_R , Square Wave, 20 kHz, $T_C = 140^\circ\text{C}$) Per Diode	I_{FM}	16	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	100	A
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-65 to +175	°C



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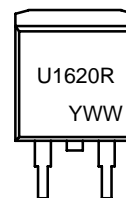
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**ULTRAFAST
RECTIFIER
16 AMPERES
200 VOLTS**



D²PAK
CASE 418B
STYLE 5

MARKING DIAGRAM



U1620R = Specific Device Code
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MURB1620CTR	D ² PAK	50 Units/Rail
MURB1620CTR4	D ² PAK	800/Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

MURB1620CTR

THERMAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Value	Unit
Thermal Resistance - Junction to Case	$R_{\theta JC}$	2.0	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS (Per Leg)

Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0$ Amps, $T_C = 25^{\circ}C$) ($i_F = 8.0$ Amps, $T_C = 150^{\circ}C$)	V_F	1.2 1.1	Volts
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 150^{\circ}C$)	i_R	5.0 500	μA
Maximum Reverse Recovery Time ($I_F = 1.0$ Amp, $di/dt = 50$ Amps/ μs) ($I_F = 0.5$ Amp, $di/dt = 100$ Amps/ μs)	t_{rr}	85 35	ns

1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle $\leq 10\%$.

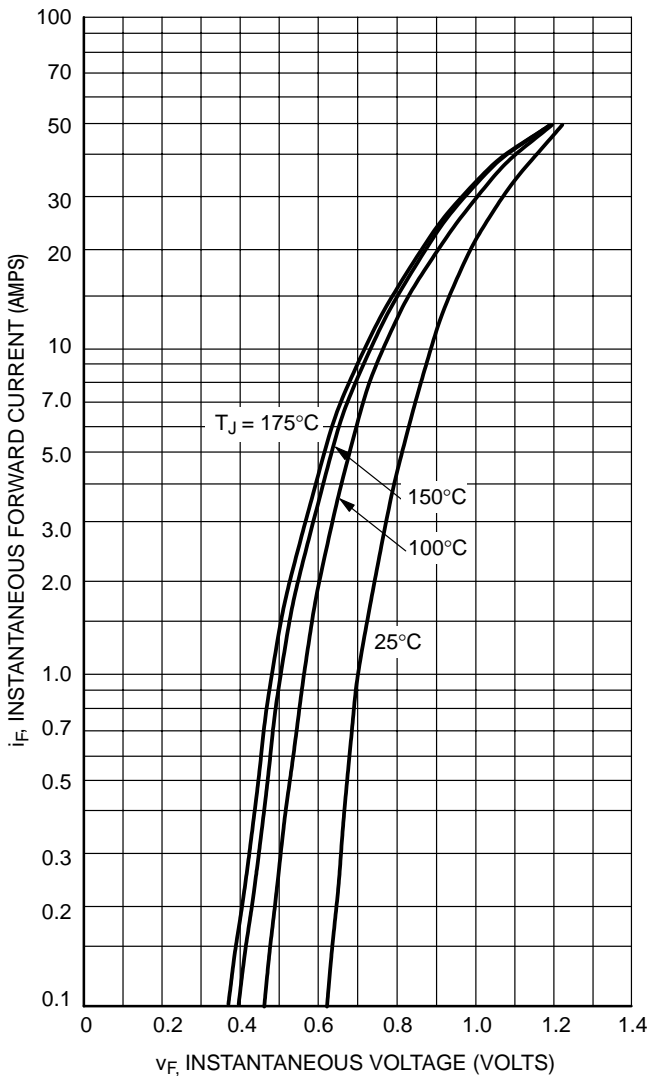


Figure 1. Typical Forward Voltage (Per Leg)

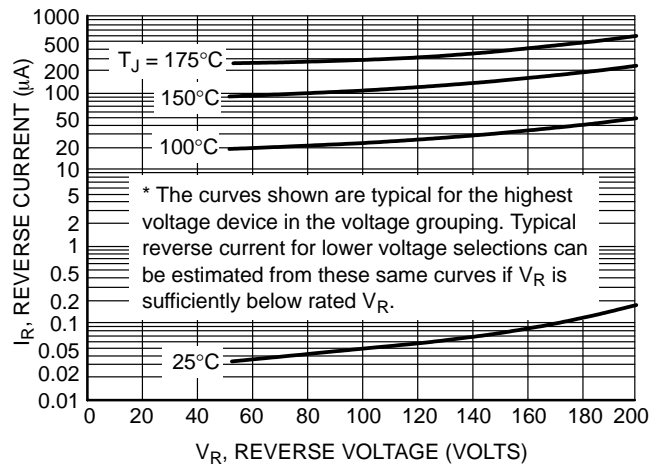


Figure 2. Typical Reverse Current* (Per Leg)

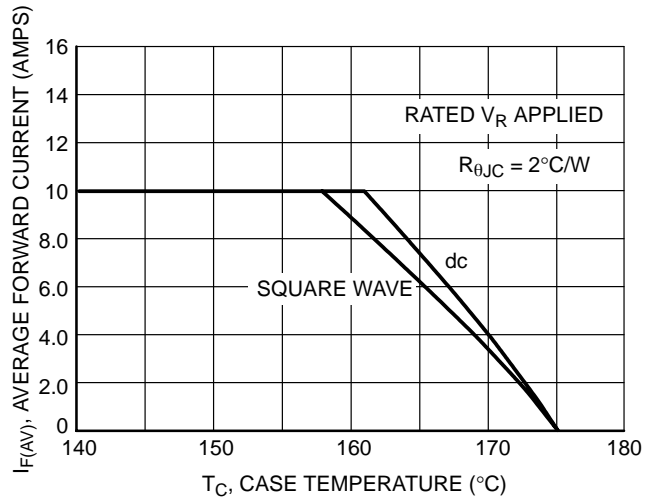
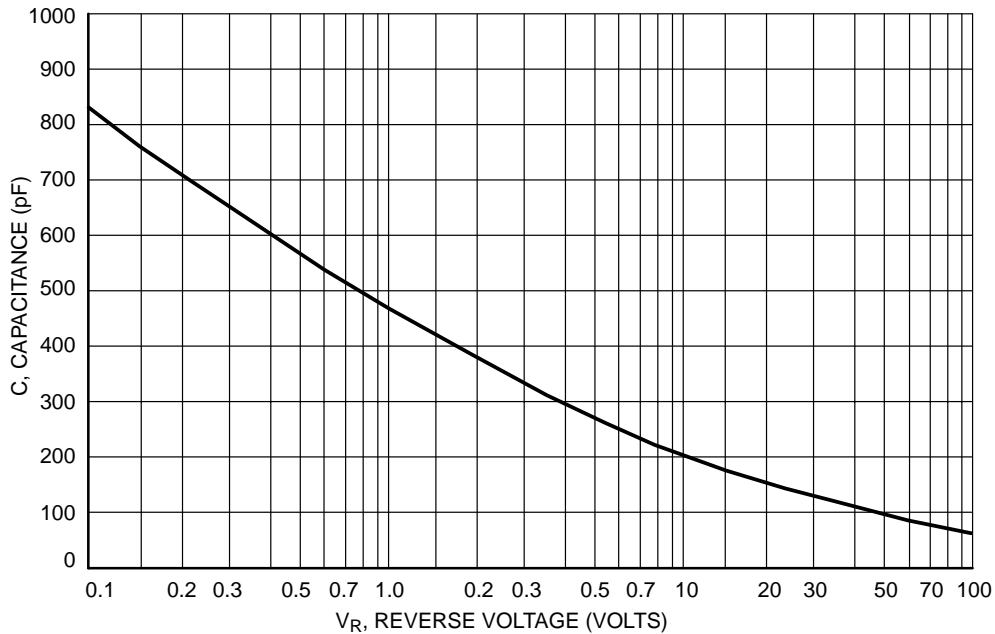
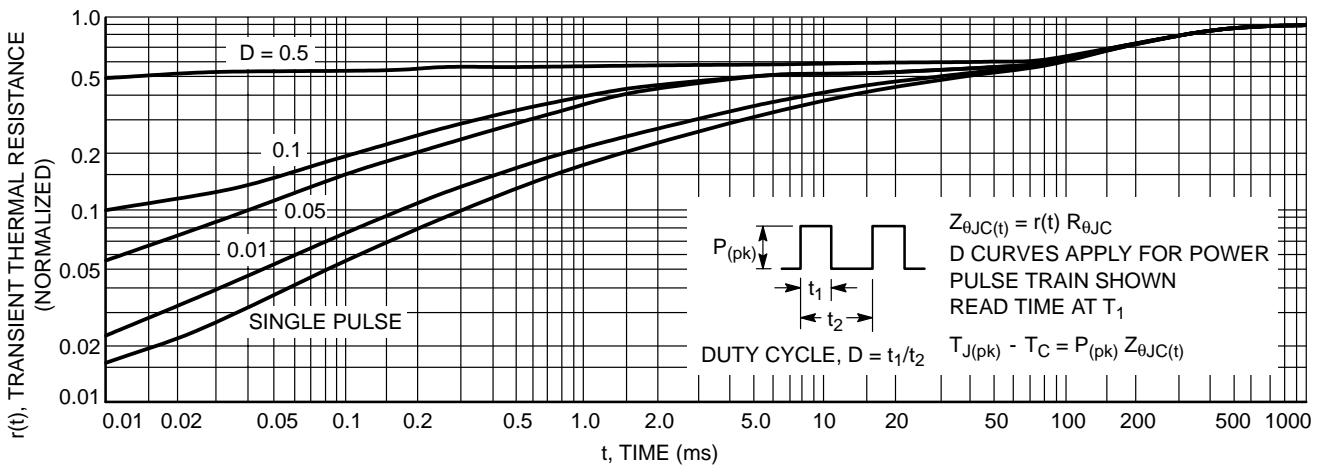
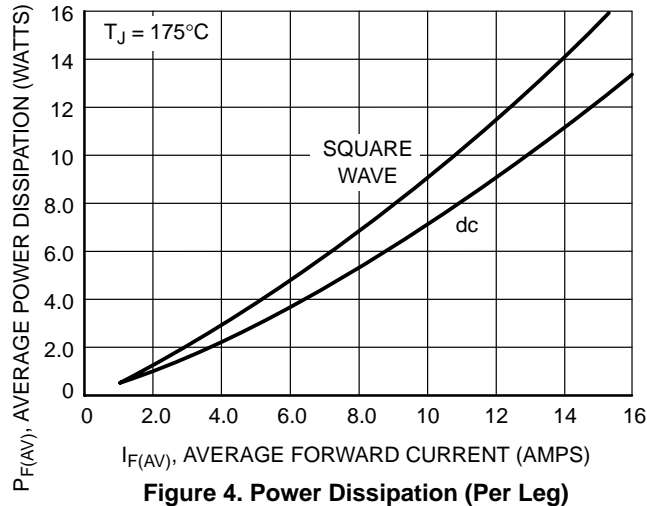


Figure 3. Current Derating, Case (Per Leg)

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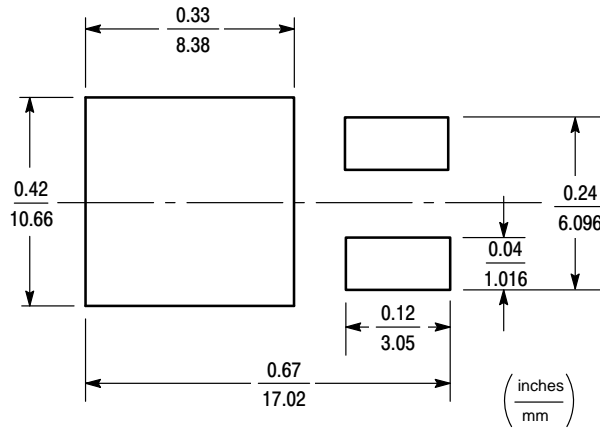


INFORMATION FOR USING THE D²PAK SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



D²PAK POWER DISSIPATION

The power dissipation of the D²PAK is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient; and the operating temperature, T_A . Using the values provided on the data sheet for the D²PAK package, P_D can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values

into the equation for an ambient temperature T_A of 25°C, one can calculate the power dissipation of the device which in this case is 3.0 watts.

$$P_D = \frac{175^\circ\text{C} - 25^\circ\text{C}}{50^\circ\text{C/W}} = 3.0 \text{ watts}$$

The 50°C/W for the D²PAK package assumes the recommended drain pad area of 158K mil² on FR-4 glass epoxy printed circuit board to achieve a power dissipation of 3.0 watts using the footprint shown. Another alternative is to use a ceramic substrate or an aluminum core board such as Thermal Clad[®]. By using an aluminum core board material such as Thermal Clad, the power dissipation can be doubled using the same footprint.

GENERAL SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 5 seconds.

- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling

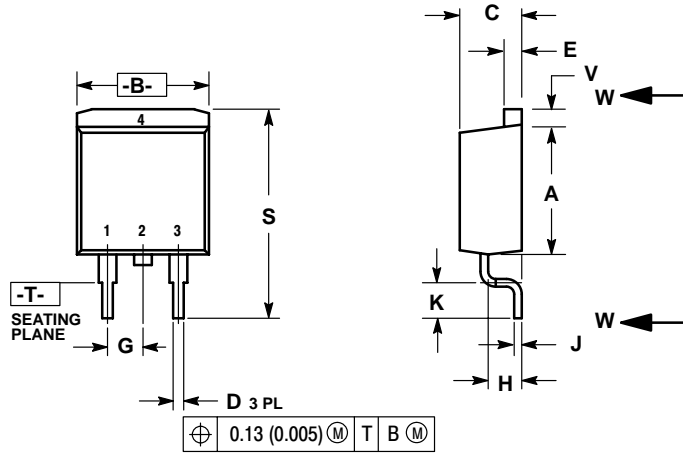
* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

* Due to shadowing and the inability to set the wave height to incorporate other surface mount components, the D²PAK is not recommended for wave soldering.

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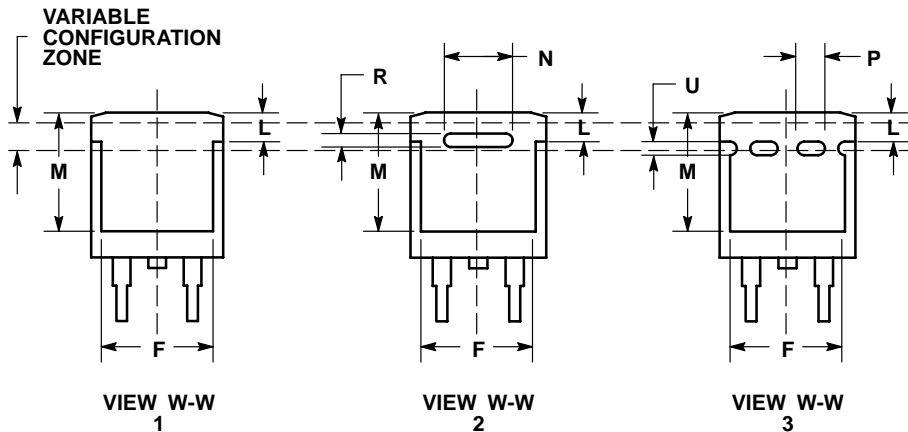
PACKAGE DIMENSIONS

D²PAK
CASE 418B-04
ISSUE H



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.340	0.380	8.64	9.65
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
E	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100	BSC	2.54	BSC
H	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
M	0.280	0.320	7.11	8.13
N	0.197	REF	5.00	REF
P	0.079	REF	2.00	REF
R	0.039	REF	0.99	REF
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40



- STYLE 5:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

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